

Amendments to the Claims

This listing of claims replaces all prior versions and listings of claims in the application:

Listing of Claims:

1. (Currently Amended) A thin film integrated circuit device comprising:
a first display area;
a thin film integrated circuit including a plurality of semiconductor films as a plurality of active region formed over an insulating film; and
a second display area that is formed over the first display area and connected to the thin film integrated circuit,
wherein the second display area is a dual emission light-emitting device.
2. (Currently Amended) A thin film integrated circuit device comprising:
a first display area;
a thin film integrated circuit including a plurality of semiconductor films as a plurality of active region formed over an insulating film; and
a second display area that is formed over the first display area and connected to the thin film integrated circuit,
wherein the second display area is a dual emission light-emitting device, and
wherein display of the first display area is visible when the second display area is OFF.
3. (Currently Amended) A thin film integrated circuit device comprising:
a first display area;
a thin film integrated circuit including a plurality of the semiconductor films as a plurality of active region formed over one surface of an insulating film;

a metal oxide provided over another one surface of the insulating film; and
a second display area that is formed over the first display area and connected to
the thin film integrated circuit,

wherein the second display area is a dual emission light-emitting device.

4. (Currently Amended) A thin film integrated circuit device comprising:
a first display area;
a thin film integrated circuit including a plurality of semiconductor films as a
plurality of active region formed over one surface of an insulating film;
a metal oxide provided over another surface of the insulating film; and
a second display area that is formed over the first display area and connected to
the thin film integrated circuit,
wherein the second display area is a dual emission light-emitting device, and
wherein display of the first display area is visible when the second display area is
OFF.

5. (Currently Amended) A thin film integrated circuit device comprising:
a first display area;
a thin film integrated circuit having a plurality of thin film transistors formed over
one surface of an insulating film;
a metal oxide provided over another one surface of the insulating film; and
a second display area that is formed over the first display area and connected to
the thin film integrated circuit,
wherein the second display area is a dual emission light-emitting device.

6. (Currently Amended) A thin film integrated circuit device comprising:
a first display area;
a thin film integrated circuit having a plurality of thin film transistors formed over

one surface of an insulating film;

a metal oxide provided over another one surface of the insulating film; and

a second display area that is formed over the first display area and connected to the thin film integrated circuit,

wherein the second display area is a dual emission light-emitting device, and

wherein display of the first display area is visible when the second display area is OFF.

7. (Original) A thin film integrated circuit device according to claim 1, wherein the first display area is a photograph.

8. (Original) A thin film integrated circuit device according to claim 2, wherein the first display area is a photograph.

9. (Original) A thin film integrated circuit device according to claim 3, wherein the first display area is a photograph.

10. (Original) A thin film integrated circuit device according to claim 4, wherein the first display area is a photograph.

11. (Original) A thin film integrated circuit device according to claim 5, wherein the first display area is a photograph.

12. (Original) A thin film integrated circuit device according to claim 6, wherein the first display area is a photograph.

13-18. (Cancelled).

19. (Original) A thin film integrated circuit device according to claim 3, wherein the metal film is formed from an element selected from the group consisting of W, Ta, Mo, Nd, Ni, Co, Zr, Zn, Ru, Rh, Pd, Os, and Ir, or an alloy material or a compound material which is based on the element; or an oxide of the metal compound.

20. (Original) A thin film integrated circuit device according to claim 4, wherein the metal film is formed from an element selected from the group consisting of W, Ti, Ta, Mo, Nd, Ni, Co, Zr, Zn, Ru, Rh, Pd, Os, and Ir, or an alloy material or a compound material which is based on the element; or an oxide of the metal compound.

21. (Original) A thin film integrated circuit device according to claim 5, wherein the metal film is formed from an element selected from the group consisting of W, Ti, Ta, Mo, Nd, Ni, Co, Zr, Zn, Ru, Rh, Pd, Os, and Ir, or an alloy material or a compound material which is based on the element; or an oxide of the metal compound.

22. (Original) A thin film integrated circuit device according to claim 6, wherein the metal film is formed from an element selected from the group consisting of W, Ti, Ta, Mo, Nd, Ni, Co, Zr, Zn, Ru, Rh, Pd, Os, and Ir, or an alloy material or a compound material which is based on the element; or an oxide of the metal compound.

23. (Original) A thin film integrated circuit device according to claim 3, wherein the metal oxide is WO₂ or WO₃.

24. (Original) A thin film integrated circuit device according to claim 4, wherein the metal oxide is WO₂ or WO₃.

25. (Original) A thin film integrated circuit device according to claim 5, wherein the metal oxide is WO₂ or WO₃.

26. (Original) A thin film integrated circuit device according to claim 6, wherein the metal oxide is WO₂ or WO₃.

27. (Original) A thin film integrated circuit device according to claim 1, wherein the first display area and the second display area are similar in size.

28. (Original) A thin film integrated circuit device according to claim 2, wherein the first display area and the second display area are similar in size.

29. (Original) A thin film integrated circuit device according to claim 3, wherein the first display area and the second display area are similar in size.

30. (Original) A thin film integrated circuit device according to claim 4, wherein the first display area and the second display area are similar in size.

31. (Original) A thin film integrated circuit device according to claim 5, wherein the first display area and the second display area are similar in size.

32. (Original) A thin film integrated circuit device according to claim 6, wherein the first display area and the second display area are similar in size.

33. (Original) A thin film integrated circuit device according to claim 1, wherein the first display area and the second display area are combined whereby displaying letters, graphics, symbols or the combination thereof.

34. (Original) A thin film integrated circuit device according to claim 2, wherein the first display area and the second display area are combined whereby displaying letters, graphics, symbols or the combination thereof.

35. (Original) A thin film integrated circuit device according to claim 3, wherein the first display area and the second display area are combined whereby displaying letters, graphics, symbols or the combination thereof.

36. (Original) A thin film integrated circuit device according to claim 4, wherein the first display area and the second display area are combined whereby displaying letters, graphics, symbols or the combination thereof.

37. (Original) A thin film integrated circuit device according to claim 5, wherein the first display area and the second display area are combined whereby displaying letters, graphics, symbols or the combination thereof.

38. (Original) A thin film integrated circuit device according to claim 6, wherein the first display area and the second display area are combined whereby displaying letters, graphics, symbols or the combination thereof.

39. (Original) A thin film integrated circuit device according to claim 1, wherein the first display area displays a static image.

40. (Original) A thin film integrated circuit device according to claim 2, wherein the first display area displays a static image.

41. (Original) A thin film integrated circuit device according to claim 3, wherein the first display area displays a static image.

42. (Original) A thin film integrated circuit device according to claim 4, wherein the first display area displays a static image.

43. (Original) A thin film integrated circuit device according to claim 5, wherein the first display area displays a static image.

44. (Original) A thin film integrated circuit device according to claim 6, wherein the first display area displays a static image.

45. (Original) A thin film integrated circuit device according to claim 1, wherein the second display area displays a moving image.

46. (Original) A thin film integrated circuit device according to claim 2, wherein the second display area displays a moving image.

47. (Original) A thin film integrated circuit device according to claim 3, wherein the second display area displays a moving image.

48. (Original) A thin film integrated circuit device according to claim 4, wherein the second display area displays a moving image.

49. (Original) A thin film integrated circuit device according to claim 5, wherein the second display area displays a moving image.

50. (Original) A thin film integrated circuit device according to claim 6, wherein the second display area displays a moving image.

51. (Original) A thin film integrated circuit device according to claim 1, wherein the thin film integrated circuit device is an IC card.

52. (Original) A thin film integrated circuit device according to claim 2, wherein the thin film integrated circuit device is an IC card.

53. (Original) A thin film integrated circuit device according to claim 3, wherein the thin film integrated circuit device is an IC card.

54. (Original) A thin film integrated circuit device according to claim 4, wherein the thin film integrated circuit device is an IC card.

55. (Original) A thin film integrated circuit device according to claim 5, wherein the thin film integrated circuit device is an IC card.

56. (Original) A thin film integrated circuit device according to claim 6, wherein the thin film integrated circuit device is an IC card.